

145 Adams Avenue, Hauppauge, NY 11788 USA Tel: (631) 435-1110 • Fax: (631) 435-1824

Manufacturers of World Class Discrete Semiconductors

2N3734 2N3735

NPN SILICON TRANSISTORS

JEDEC TO-39 CASE

DESCRIPTION

The CENTRAL SEMICONDUCTOR 2N3734, 2N3735 types are Silicon NPN Transistors in a hermetically sealed case designed for core driver and high speed switching applications.

MAXIMUM RATINGS (TA=25°C unless otherwise noted)

	SYMBOL	<u>2N3734</u>	2N3735	UNIT
Collector-Base Voltage	V _{CBO}	50	75	V
Collector-Emitter Voltage	VCEO	30	50	٧
Emitter-Base Voltage	VEBO	5.0	5.0	٧.
Collector Current	Ic	1.5	1.5	Α
Power Dissipation	P _D	1.0	1.0	W
Power Dissipation (T _C =25°C)	P_{D}^{-}	4.0	4.0	W
Operating and Storage				
Junction Temperature	Tj, T _{stg}	-65 TO +200		°C
Thermal Resistance	θЈΑ	175	175	°C/W
Thermal Resistance	θJC	43.75	43.75	°C/W

ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted) 2N3734 2N3735						
SYMBOL	TEST CONDITIONS	MIN	MAX	MIN	MAX	UNIT
CEV CEV CEV BL BVCBO	V _{CE} =25V, V _{EB} =2.0V V _{CE} =25V, V _{EB} =2.0V, T _A =100°C V _{CE} =40V V _{EB} =2.0V V _{CE} =40V, V _{EB} =2.0V, T _A =100°C V _{CE} =25V, V _{EB} =2.0V V _{CE} =40V, V _{EB} =2.0V I _C =10µA	50	200 20 - - 300	75	200 20 - 300	nA μA nA μA nA nA
BVCEO BVEBO VCE(SAT) VCE(SAT) VCE(SAT) VCE(SAT) VBE(SAT) VBE(SAT) VBE(SAT)	I C=10mA I E=10μA I C=10mA, I B=1.0mA I C=150mA, I B=15mA I C=500mA, I B=50mA I C=1.0A, I B=100mA I C=10mA, I B=1.0mA I C=150mA, I B=15mA I C=500mA, I B=50mA	30 5.0	0.2 0.3 0.5 0.9 0.8 1.0	50 5.0	0.2 0.3 0.5 0.9 0.8 1.0	V V V V V V
VBE(SAT) hFE hFE hFE hFE hFE hFE hFE	Ic=1.0A, I _B =100mA V _{CE} =1.0V, I _C =10mA V _{CE} =1.0V, I _C =150mA V _{CE} =1.0V, I _C =500mA V _{CE} =1.5V, I _C =1.0A V _{CE} =5.0V, I _C =1.5A	0.9 35 40 35 30 30	1.4	0.9 35 40 35 20 20	1.4	V MU_
Cob Cib ton toff QT	VCE=10V, IC=50mA, f=100MHz VCB=10V, IE=0, f=100kHz VBE=0.5V, IC=0, f=100kHz VCC=30V, VBE(0FF)=2.0V, IC=1.0A, IB1=100mA VCC=30V, IC=1.0A, IB1= IB2=100mA VCC=30V, IC=1.0A, IB=100mA	250	9.0 80 48 60	250	9.0 80 48 60	MHz pF pF ns ns

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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